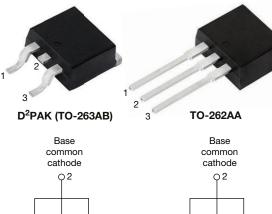
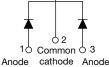
VS-40CTQ150S-M3, VS-40CTQ150-1-M3

Vishay Semiconductors

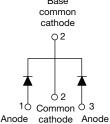
High Performance Schottky Rectifier, 2 x 20 A



www.vishay.com



SHAY



VS-40CTQ150S-M3

VS-40CTQ150-1-M3

PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 20 A							
V _R	150 V							
V _F at I _F	0.71 V							
I _{RM}	15 mA at 125 °C							
T _J max.	175 °C							
E _{AS}	1 mJ							
Package	D ² PAK (TO-263AB), TO-262AA							
Circuit configuration	Common cathode							

FEATURES

- Very low forward voltage drop
- 175 °C T_{.1} operation
- Center tap TO-220 package
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-40CTQ... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	40	А					
V _{RRM}		150	V					
I _{FSM}	t _p = 5 μs sine	1500	А					
V _F	20 A_{pk} , T_J = 125 °C (per leg)	0.71	V					
TJ		-55 to +175	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-40CTQ150S-M3 VS-40CTQ150-1-M3	UNITS					
Maximum DC reverse voltage	V _R	150	V					
Maximum working peak reverse voltage	V _{RWM}	150	v					

Revision: 21-Dec-2021 Document Number: 95732 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



COMPLIANT HALOGEN FREE



Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward per leg			50 % duty cycle at T _C = 140 °		20				
current, see fig. 5	per device	IF(AV)	50% ulty cycle at $1_{\rm C} = 140\%$	40	А				
Maximum peak one cycle non-repetitive surge current per leg, see fig. 7			5 µs sine or 3 µs rect. pulse	Following any rated		1500			
		I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied		250			
Non-repetitive avalanche energy	r per leg	E _{AS}	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 1.5 \ A, \ L = 0.5 \ A$.9 mH	1.0	mJ			
Repetitive avalanche current per	leg	I _{AR}	Current decaying linearly to z Frequency limited by T _J maxi typical	1.5	А				

ELECTRICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS							
		20 A	T, = 25 °C	0.93						
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	40 A	1j=25 C	1.16	V					
	VFM (*)	20 A	T, = 125 °C	0.71						
		40 A	1j = 125 C	0.85						
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	50	μA					
See fig. 2	IRM (")	T _J = 125 °C	V _R = naleu V _R	15	mA					
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		450	pF					
Typical series inductance per leg	L _S	Measured lead to lead 5 n	8.0	nH						
Maximum voltage rate of change	dV/dt	Rated V _R	Rated V _R 10 000							

Note

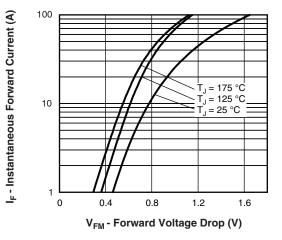
⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperat	ure range	T _J , T _{Stg}		-55 to +175	°C				
Maximum thermal resistance, junction to case per leg		- R _{thJC}	DC operation See fig. 4	1.5					
Maximum thermal resistance, junction to case per package		nthJC	DC operation	0.75	°C/W				
Typical thermal resistance, case to heats	Typical thermal resistance, case to heatsink		Mounting surface, smooth and greased	0.5					
Approximate weight				2	g				
Approximate weight				0.07	oz.				
Mounting torque minimum maximum			Non-lubricated threads	6 (5)	kgf ⋅ cm				
			Non-hubilicated tilleads	12 (10)	(lbf · in)				
Maulia a davia a			Case style D ² PAK (TO-263AB)	40CTQ150S					
Marking device			Case style TO-262AA	40CTC	150-1				



VS-40CTQ150S-M3, VS-40CTQ150-1-M3

Vishay Semiconductors



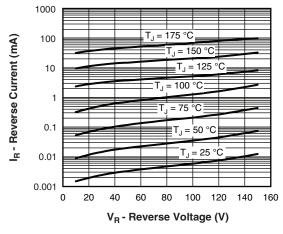


Fig. 1 - Maximum Forward Voltage Drop Characteristics



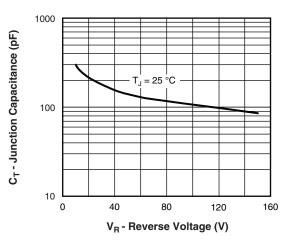


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

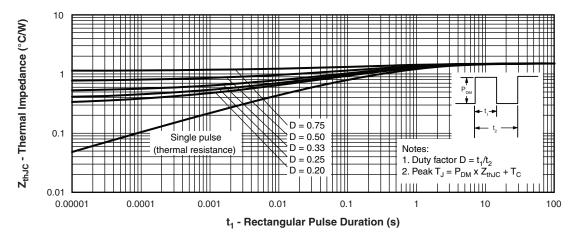
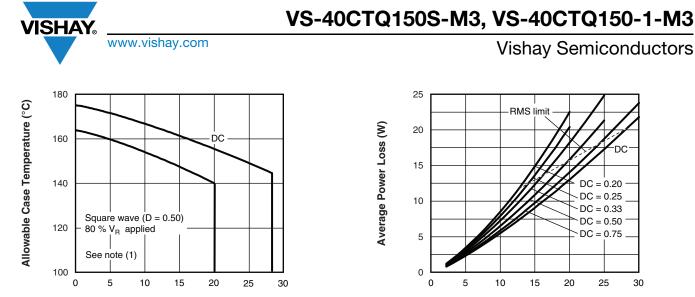


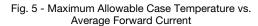
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

 Revision: 21-Dec-2021
 3
 Document Number: 95732

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000









DC

30

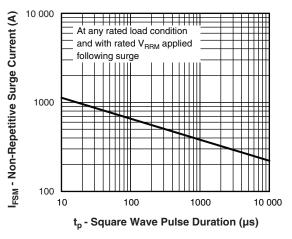
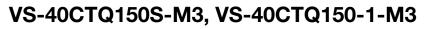


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

- (1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 - $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{V}_{\mathsf{R}} \ \mathsf{applied} \end{array}$



Vishay Semiconductors

ORDERING INFORMATION TABLE

www.vishay.com

SHAY

.				_			_		
Device code	VS-	40	С	T	Q	150	S	TRL	-M3
	1	2	3	4	5	6	7	8	9
	1	- Visl	nav Sen	nicondu	ctors pro	oduct			
	2		-	ng (40 A					
	3.	 Circuit configuration: C = common cathode T = TO 220 							
	4	- T=	TO-220)					
	5	- Sch	ottky "C)" series					
	6	- Vol	tage rati	ing (150	= 150 \	/)			
	7	• s	= D ² PA	К (ТО-2	263AB)				
		• -1	= TO-2	62AA					
	8	• N	one = tu	ıbe (50 j	oieces)				
		• TI	RL = tap	be and r	eel (left	oriented	d - for D	² PAK (⁻	TO-263
		• T	RR = ta	pe and r	eel (righ	nt orient	ed - for	D ² PAK	(TO-26
	9	M3	s = halog	gen-free	, RoHS	-complia	ant, and	d termin	ation le

ORDERING INFORMATION (Example)									
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION							
VS-40CTQ150S-M3	50	Antistatic plastic tubes							
VS-40CTQ150STRL-M3	800	13" diameter plastic tape and reel							
VS-40CTQ150STRR-M3	800	13" diameter plastic tape and reel							
VS-40CTQ150-1-M3	50	Antistatic plastic tubes							

LINKS TO RELATED DOCUMENTS									
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164							
	TO-262AA	www.vishay.com/doc?96165							
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444							
	TO-262AA	www.vishay.com/doc?95443							
Packaging information		www.vishay.com/doc?96424							
SPICE model		www.vishay.com/doc?95434							

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

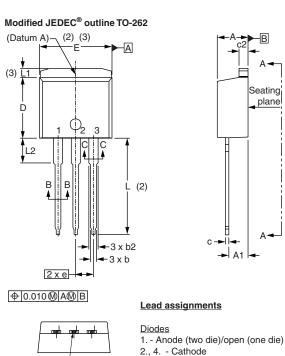
Outline Dimensions



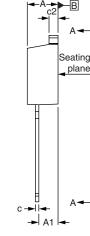
Vishay Semiconductors

TO-262

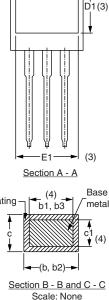
DIMENSIONS in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 _ 1.65 0.065 3 _ 3.36 0.132 0.146 L2 3.71

3. - Anode

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019

Document Number: 95419

1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.